TOSHIBA

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSIV)

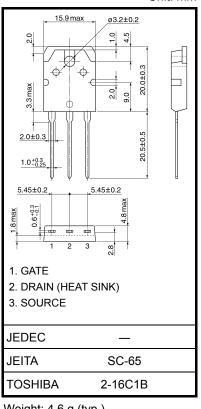
2SK3473

Switching Regulator Applications

- Low drain-source ON-resistance: R_{DS} (ON) = 1.3 Ω (typ.)
- High forward transfer admittance: |Y_{fs}| = 6.5 S (typ.)
- Low leakage current: I_{DSS} = 100 μ A (max) (V_{DS} = 720 V)
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

| Characteristics | | Symbol | Rating | Unit | |
|-----------------------|--------------------------|------------------|------------|------|--|
| Drain-source voltage | | V _{DSS} | 900 | V | |
| Drain-gate voltage (F | R _{GS} = 20 kΩ) | V _{DGR} | 900 | V | |
| Gate-source voltage | | V _{GSS} | ±30 | V | |
| Drain current | DC (Note 1) | ۱ _D | 9 | Α | |
| | Pulse (Note 1) | I _{DP} | 27 | A | |
| Drain power dissipat | ion (Tc = 25°C) | PD | 150 | W | |
| Single pulse avalanc | he energy (Note 2) | E _{AS} | 413 | mJ | |
| Avalanche current | | I _{AR} | 9 | А | |
| Repetitive avalanche | e energy (Note 3) | E _{AR} | 15 | mJ | |
| Channel temperature | 9 | T _{ch} | 150 | °C | |
| Storage temperature | range | T _{stg} | -55 to 150 | °C | |

Absolute Maximum Ratings (Ta = 25°C)



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

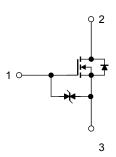
| Characteristics | Symbol | Max | Unit | |
|--|------------------------|-------|------|--|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W | |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W | |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25 ^{\circ}C (initial), L = 9.35 mH, I_{AR} = 9 A, R_G = 25 Ω

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.



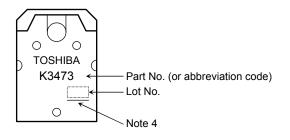
Electrical Characteristics (Ta = 25°C)

| Char | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|---------------|----------------------|--|-----|------|-----|------|
| Gate leakage current | | I _{GSS} | $V_{GS}=\pm 25~V,~V_{DS}=0~V$ | _ | | ±10 | μA |
| Gate-source breakdown voltage | | V (BR) GSS | $I_D=\pm 10~\mu A,~V_{DS}=0~V$ | ±30 | | | V |
| Drain cut-off current | | IDSS | $V_{DS} = 720 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | | 100 | μA |
| Drain-source breakdown voltage | | V (BR) DSS | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$ | 900 | | | V |
| Gate threshold voltage | | V _{th} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$ | 2.0 | | 4.0 | V |
| Drain-source ON | resistance | R _{DS (ON)} | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$ | | 1.3 | 1.6 | Ω |
| Forward transfer | admittance | Y _{fs} | $V_{DS} = 15 \text{ V}, \text{ I}_{D} = 4 \text{ A}$ | 3.0 | 6.5 | _ | S |
| Input capacitance | | C _{iss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | | 1450 | | pF |
| Reverse transfer capacitance | | C _{rss} | | | 30 | | |
| Output capacitance | | C _{oss} | | | 155 | | |
| Switching time | Rise time | tr | $V_{GS} \\ 0 \\ V \\ 4.7 \\ \Omega \\ W_{DD} \approx 400 $ | _ | 30 | _ | |
| | Turn-on time | t _{on} | | | 55 | | |
| | Fall time | t _f | | _ | 12 | _ | ns |
| | Turn-off time | t _{off} | Duty \leq 1%, t _w = 10 μ s | _ | 75 | _ | |
| Total gate charge | | Qg | | _ | 38 | _ | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 9 \text{ A}$ | _ | 22 | _ | nC |
| Gate-drain charge | | Q _{gd} |] | | 16 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | — | _ | _ | 9 | А |
| Pulse drain reverse current (Note 1) | I _{DRP} | — | _ | | 27 | А |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 9 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 9 A, V _{GS} = 0 V, | _ | 1350 | _ | ns |
| Reverse recovery charge | Qrr | dl _{DR} /dt = 100 A/μs | _ | 15 | _ | μC |

Marking



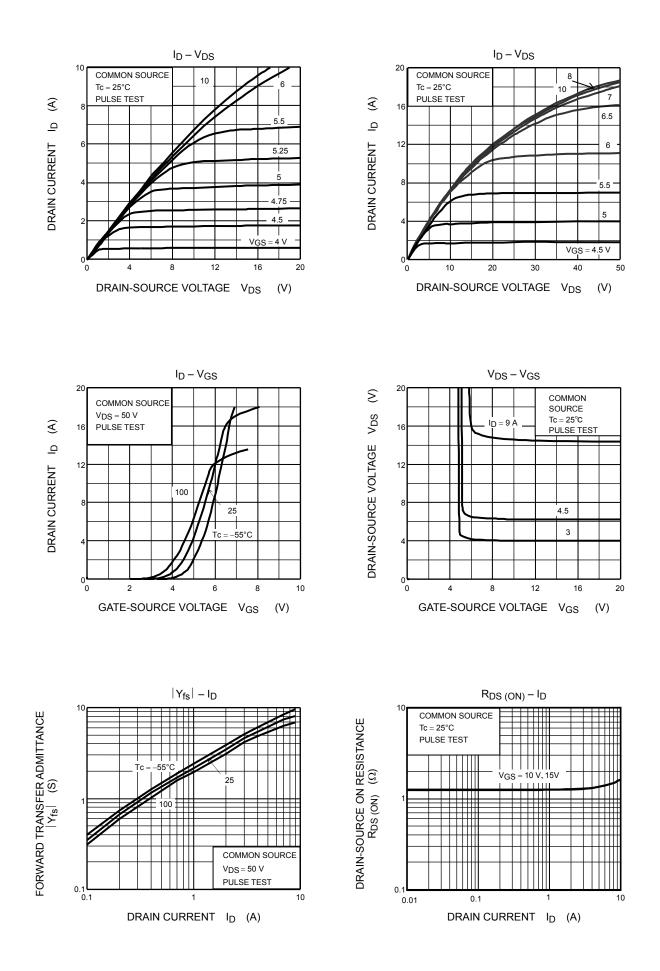
Note 4: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

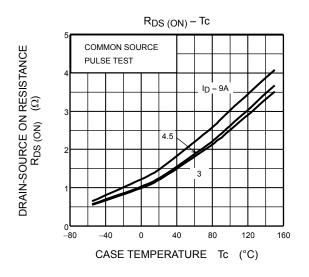
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

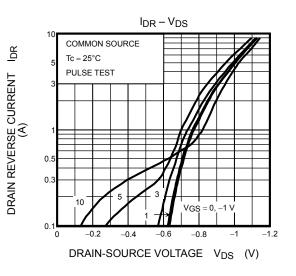
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

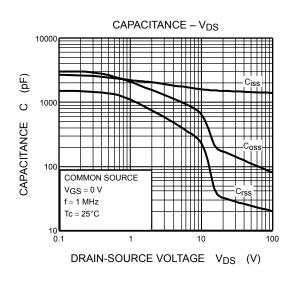
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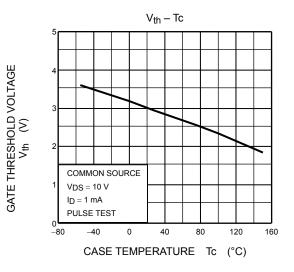


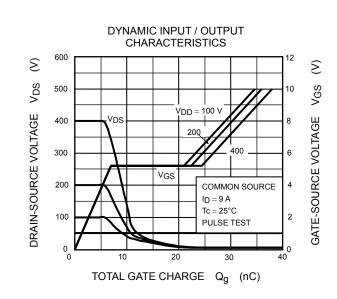
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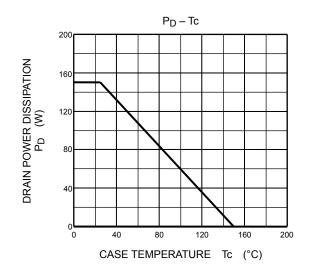


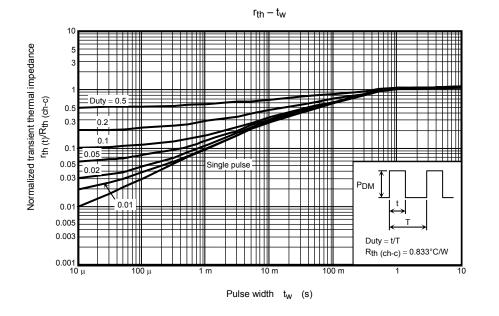


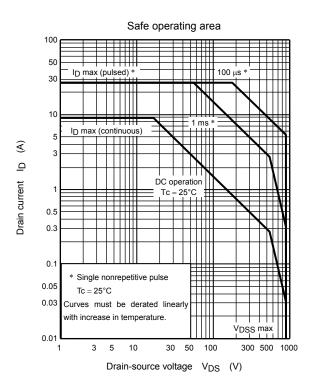


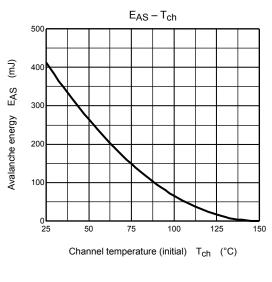


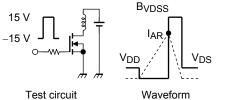












 $\begin{array}{l} \mathsf{R}_{G} = 25 \ \Omega \\ \mathsf{V}_{DD} = 90 \ \mathsf{V}, \ \mathsf{L} = 9.35 \ \mathsf{mH} \end{array} \qquad \mathsf{E}_{AS} = \frac{1}{2} \cdot \mathsf{L} \cdot \mathsf{I}^{2} \cdot \left(\frac{\mathsf{B}_{VDSS}}{\mathsf{B}_{VDSS} - \mathsf{V}_{DD}} \right) \end{array}$

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